

Sheet 1 of 1

Form PTO- 1449	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DKT. NO. 501.35478CX23	SERIAL NO. 10/810,624
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (Use several sheets if necessary)		APPLICANT	
		Miwa, et al.	
		FILING DATE March 29, 2004	GROUP 2818-2827

**U.S. PATENT DOCUMENTS**

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date
AA						
AB						
AC						
AD						
AE						
AF						
AG						
AH						
AI						
AJ						
AK						
AL						

**FOREIGN PATENT DOCUMENTS**

Examiner Initial	Document Number	Date	Country	Class	Subclass	Abstract	
						Yes	No
MG	AM 3-237692	10-23-91	JP			X	
MG	AN 11-025682	1-29-99	JP			X	
MV	AO 07-093979	04-07-95	JP			X	
	AP						
	AQ						
	AR						
	AS						
	AT						

**OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)**

AU	
AV	
AW	
AX	
AY	
AZ	

Examiner M. TRAU	Date Considered 9/2/05
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10/8102624

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Commerce(Rev. 4/92) Patent and Trademark  
Office

**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

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ATTY. DOCKET NO.  
501.35478CX23

SERIAL NO.

Not yet assigned 10/810624

APPLICANT  
MIWA, et al

FILING DATE  
March 29, 2004

GROUP  
2848 2827

**U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER							DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
MK		4	9	6	4	0	7	9	10/90	Devin			
		5	3	6	5	4	8	6	11/94	Schreck			
		5	4	1	2	6	0	1	5/95	Sawada et al	365	185.03	
		5	8	3	1	9	0	0	11/98	Miyamoto	365	185.03	
MK		5	7	4	5	4	0	9	4/98	Wong et al	365	185.03	
		5	5	5	5	2	0	4	9/96	Endoh et al	365	189.01	
		5	1	5	1	3	8	7	9/92	Brady et al	437	191	4/30/90
		5	0	8	4	4	1	7	1/92	Joshi et al	437	192	3/13/89
MK		5	0	5	9	5	5	4	10/91	Spinner et al	437	193	6/23/89
		5	1	7	2	3	3	8	12/92	Mehrotra et al			
		5	1	3	8	5	7	6	8/92	Madurawe			
AK		5	4	8	7	0	3	6	1/96	Akaogi et al	365	185.23	

**FOREIGN PATENT DOCUMENTS**

		DOCUMENT NUMBER							DATE	COUNTRY	CLASS	SUBCLASS	ABSTRACT		
		YES	NO												
BLT	5	9	1	2	1	6	9	6	7/84	Japan				XX	
	4	2	3	8	1	9	6		8/92	Japan				XX	
AK	4	5	7	2	9	4			2/92	Japan				XX	

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MK	Digest of Technical Papers, ATP 2.1: A 3.3V 128Mb Multi-level NAND Flash Memory for Mass Storage Applications, T. Jung, et al., ISSCC96/Session 2/Flash Memory/Paper TP 2.1, 1996 EEE International Solid State Circuits Conf.
AK	Betty Prince, "Semiconductor Memories", 1983, Wisely, 2 <sup>nd</sup> Edition, pp. 620-621.

EXAMINER M. TRAN DATE CONSIDERED 9/6/05

EXAMINER: Initial if citation is considered, draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.